

High Power Switch with Integrated Bias Controller

0.5 - 8 GHz



MAMF-011180

Rev. V2

Features

- Broadband Performance
- Low Loss:
 - TX = 0.35 dB @ 3.5 GHz
 - RX = 0.4 dB @ 3.5 GHz
- High Isolation:
 - RX = 45 dB @ 3.5 GHz
- Up to 70 W CW Power Handling @ +105°C
- Fast Switching Speed
- Single +5 V DC Supply
- Compatible with 1.8 V and 3.3 V logic
- Lead-Free 5 mm 20-Lead HQFN Package
- RoHS* Compliant

Applications

- TDD 4G/5G Macro Base Stations
- Aerospace and Defense
- TDD-based communication systems

Description

The MAMF-011180 is a high power broadband PIN diode SPDT switch with a 5 V power management chip designed for 0.5 to 8 GHz high power applications.

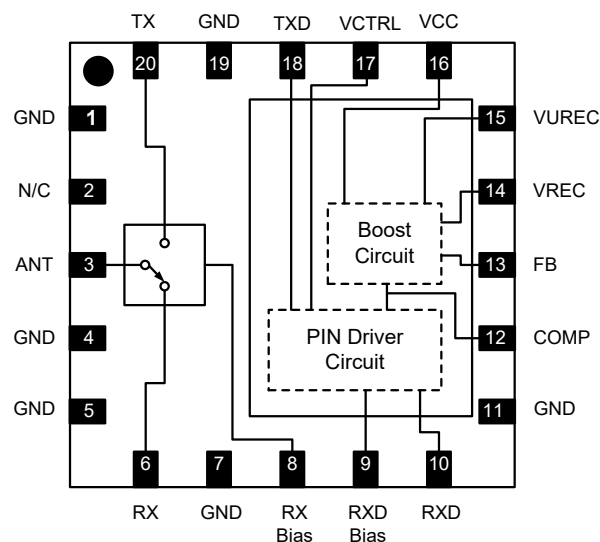
The device features low insertion loss, high isolation with low DC power consumption. It has an integrated bias controller utilizing a boost circuit. This switch requires only a single 5 V supply, and a single TX / RX control signal that is compatible with 1.8 V or 3.3 V logic.

Ordering Information¹

Part Number	Package
MAMF-011180-TR1000	1000 Piece Reel
MAMF-011180-001SMB	Sample Board

1. Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

Pin #	Function
1, 4, 5, 7, 11, 19	Ground
2	No Internal Connection ²
3	RF Input
6	RX Output / Series Bias
8	RX Shunt Bias
9	RX Shunt Driver Output
10	RX Series Driver Output
12	DC-DC Comp
13	DC-DC Feedback
14	DC-DC Boost Voltage
15	DC-DC VUREC
16	5 V Supply
17	T/R Logic Control
18	TX Driver Output
20	TX Output / Bias
21	Paddle ³

2. Pin 2 may be connected to the ANT trace on a PCB without affecting the performance.

3. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

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Pin Description

Pin #	Name	Description
1, 4, 5, 7, 11, 19	GND	These pins are grounded internally.
2	N/C	Not connected internally. May be connected to the ANT trace on a PCB without affecting RF performance.
3	ANT	Antenna RF Port and DC Bias input pin, requires resistors and choke inductor to set the diode bias current and DC blocking cap.
6	RX	RX output port and RX series diode DC bias input pin, requires choke inductor for bias and DC blocking cap.
8	RX BIAS	RX shunt diode bias input pin, requires choke inductor for bias and decoupling cap.
9	RXD BIAS	Driver output voltage pin for RX shunt diode, requires resistors to set the bias current.
10	RXD	Driver output voltage pin for RX series diode.
12	COMP	Internal DC boost compensation pin.
13	FB	Internal DC boost feedback Pin.
14	VREC	Rectified output voltage pin of the internal DC boost.
15	VUREC	Unrectified output voltage pin of the internal DC boost.
16	VCC	5 V Supply for Internal DC boost and driver, requires decoupling capacitors
17	VCTRL	T/R switching logic control.
18	TXD	Driver output voltage pin for TX diode.
20	TX	TX Input or 50 Ohm load port and DC bias input pin, requires choke inductor for bias and DC blocking cap.
21	Paddle	Ground ³

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Electrical Specifications: Freq. = 3.5 GHz, $T_A = +25^\circ\text{C}$, $V_{CC} = 5\text{ V}$, $Z_0 = 50\ \Omega$,
TX mode: ANT to TX ON, $V_{CTRL} = 1.2\text{ V}$, V_{CC} Current = 150 mA⁴;
RX mode: ANT to RX ON, $V_{CTRL} = 0.6\text{ V}$, V_{CC} Current = 100 mA⁴;

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Insertion Loss	ANT to TX ON ANT to RX ON	dB	—	0.3 0.4	0.6 0.8
Isolation	ANT to RX (TX mode) ANT to TX (RX mode)	dB	37 —	45 17	—
ANT Input Return Loss	ANT to RX ON ANT to TX ON	dB	—	17 18	—
TX Output Return Loss	ANT to TX ON	dB	—	17	—
RX Output Return Loss	ANT to RX ON	dB	—	16	—
Input P-0.1 dB	ANT to TX ON	dBm	—	48	—
Switching Speed TX ON T_{RISE} T_{FALL}	DC ctrl Pulse Rate = 500 KHz, PW = 1 μs 10% to 90% RF 90% to 10% RF	ns	—	230 190	—
Switching Speed TX ON T_{ON} T_{OFF}	DC ctrl Pulse Rate = 500 KHz, PW = 1 μs 50% VCTRL to 90% RF 50% VCTRL to 10% RF	ns	—	350 310	—
Switching Speed RX ON T_{RISE} T_{FALL}	DC ctrl Pulse Rate = 500 KHz, PW = 1 μs 10% to 90% RF 90% to 10% RF	ns	—	170 90	—
Switching Speed RX ON T_{ON} T_{OFF}	DC ctrl Pulse Rate = 500 KHz, PW = 1 μs 50% VCTRL to 90% RF 50% VCTRL to 10% RF	ns	—	340 210	—
Group Delay	—	ns	—	50	—
In-band Ripple	20 MHz 200 MHz	dB	—	0.05 0.1	—

4. The average current is set with external resistors: R1, R2, R3, and R4 as shown in the sample board schematic. The resistor values can be adjusted higher to reduce the V_{CC} average current.

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Truth Table

ANT – TX	ANT – RX	VCTRL
ON	OFF	HIGH (1.2 - 3.6 V)
OFF	ON	LOW (0 - 0.6 V)

- Please observe the following precautions to avoid damage:

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Parameter	Rating	Standard
Human Body Model (HBM)	500 V (Class 1B)	ESDA / JEDEC JS-001
Charged Device Model (CDM)	1000 V (Class C3)	JEDEC JESD22-C101

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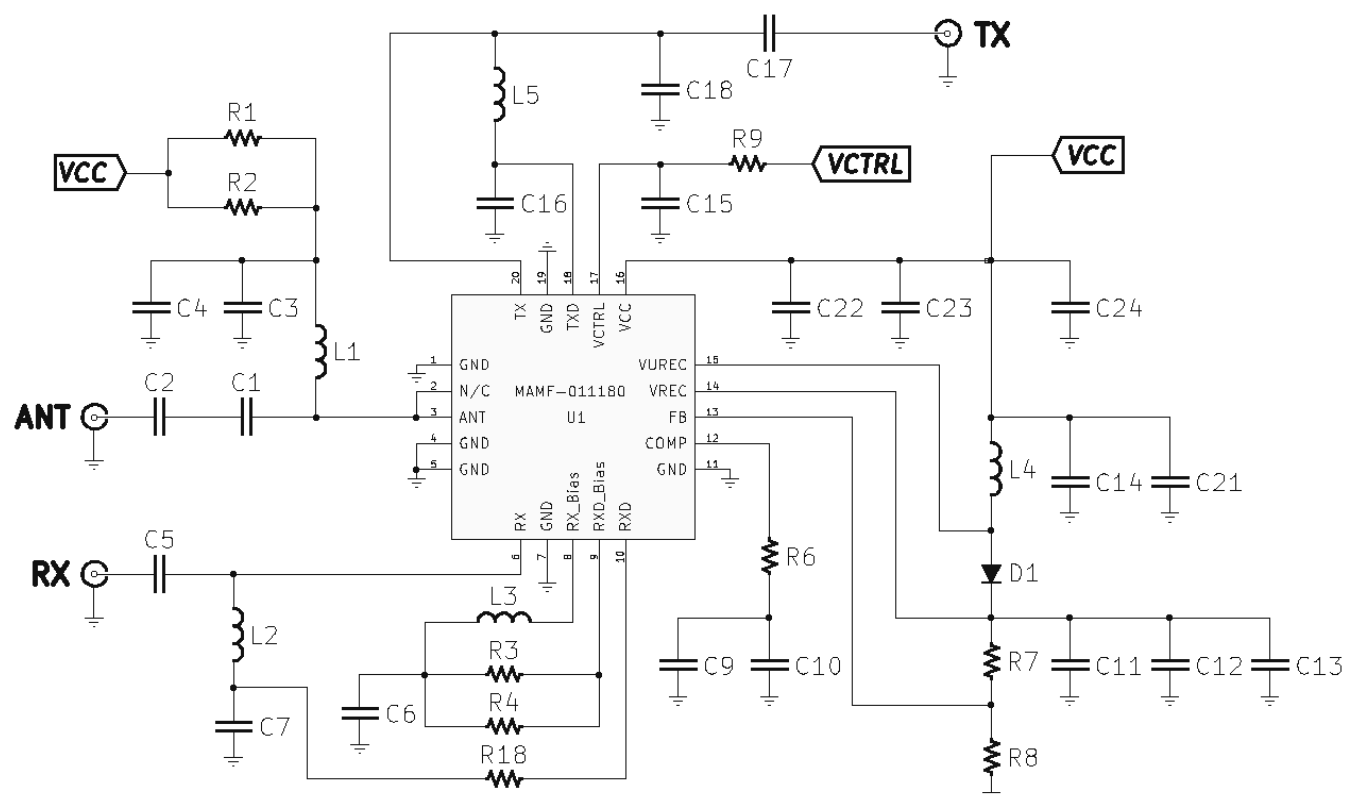


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Application Schematic

NOTE: Contact factory for sample board layout including considerations for thermal dissipation through the PCB.



Switch Biasing Information

R1 and R2 are used to set the forward bias current (I_F) of the TX or the RX series diode.

The I_F controls the Insertion Loss of the ANT to TX or ANT to RX path respectively.

For $R1 = R2 = 69.8 \Omega$ the $I_F = 0.1 \text{ A}$

$R1 = R2 = 2 * (VCC - 1.52 \text{ V}) / I_F$

These resistors must meet the following power requirement: $P_{R1/2} > (0.5 * I_F)^2 * R1$

R3 and R4 are used to set the forward bias current (I_{FSD}) in the RX shunt diode of the switch.

The I_{FSD} controls the RX isolation.

For $R3 = R4 = 3.6 \text{ k}\Omega$ the $I_{FSD} = 0.01 \text{ A}$

$R3 = R4 = 2 * (18 \text{ V}) / I_F$

These resistors must meet the following power requirement: $P_{R3/4} > (0.5 * I_{FSD})^2 * R3$

Boost Biasing Information

D1 diode requirements:

$V_B = 40 \text{ V}$,

Forward Current = 200 mA,

Forward Surge Current = 750 mA,

Reverse Leakage Current $< 400 \mu\text{A}$ @ $+125^\circ\text{C}$

During boost period, VUREC (pin 15) transient peak voltage and current can be as high as 24 V and 750 mA. Use recommended components from Parts List for proper current handling.

R7 and R8 are a resistive divider used to set the boost voltage. Use recommended components from Parts List for proper boost performance.

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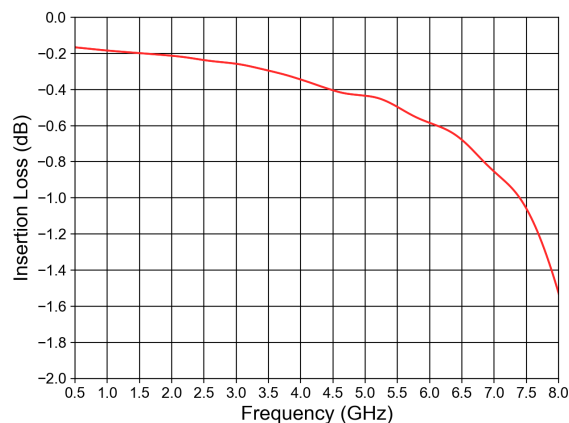
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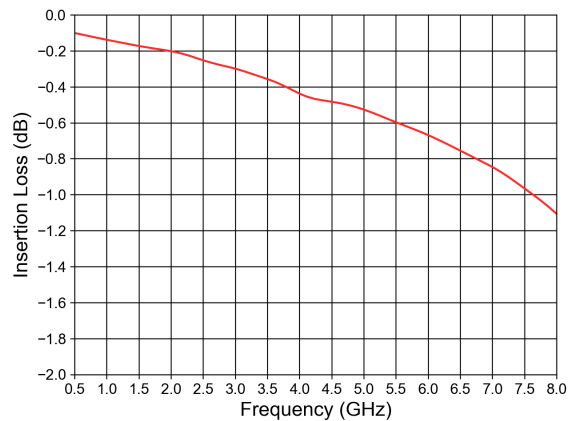
Typical Performance Curves - Probed on the Sample Board (no PCB Bias Components)

$T_C = 25^\circ\text{C}$

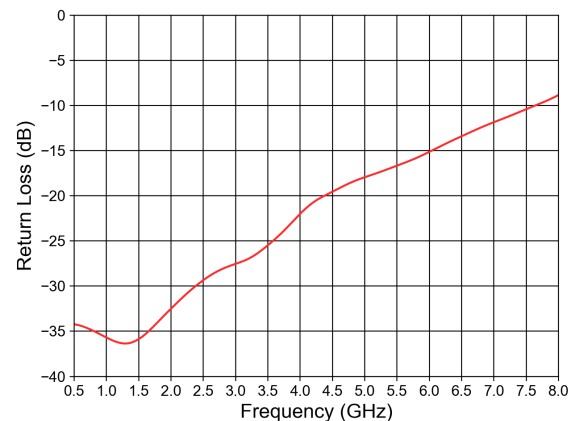
ANT to TX Insertion Loss



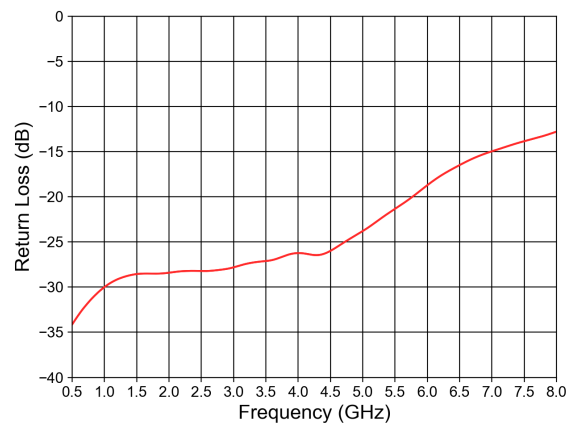
ANT to RX Insertion Loss



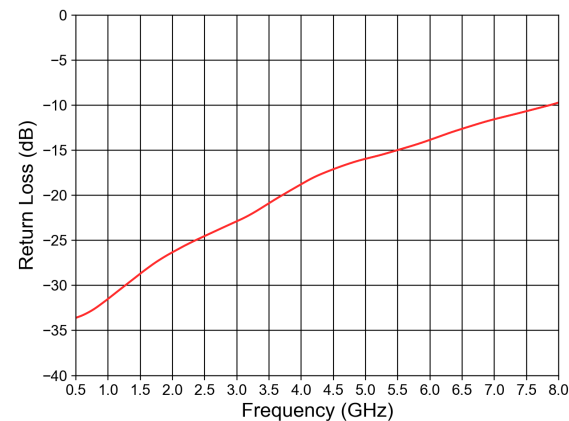
ANT Return Loss in TX ON state



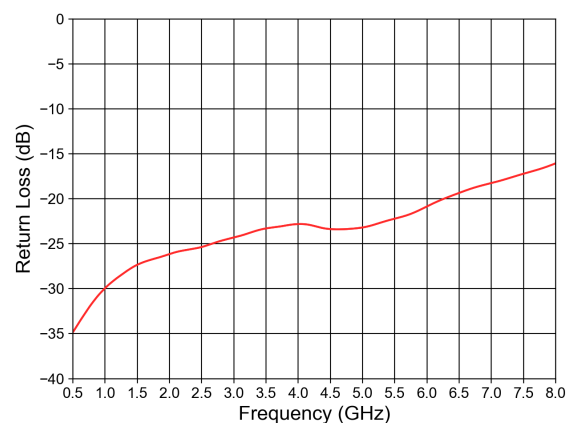
ANT Return Loss in RX ON state



TX Return Loss in TX ON state



RX Return Loss in RX ON state



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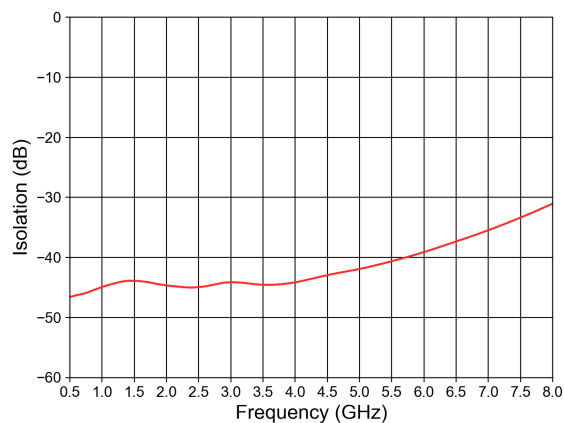
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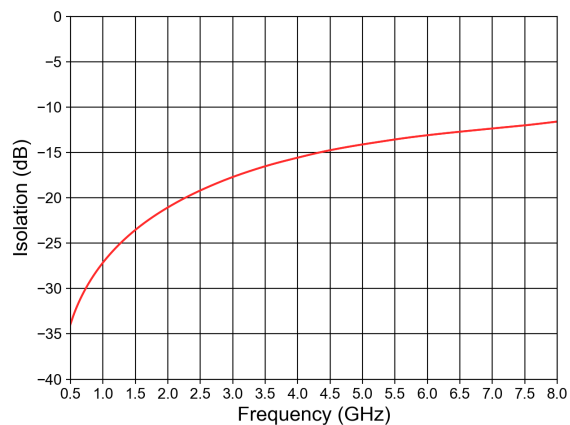
Typical Performance Curves - Probed on the Sample Board (no PCB Bias Components)

$T_c = 25^\circ\text{C}$

ANT to RX Isolation



ANT to TX Isolation



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Parts List for Sample Board (MAMF-011180-001SMB) Optimized for 1.0 - 4.2 GHz⁸

Component ID	Value	Package	Part Number	Manufacturer	Spec
MAMF-011180	—	HQFN-20LD 5 mm	MAMF-011180	MACOM	—
L1, L2	40 nH	1 x 0.5 mm	0402CS-40NXJRW	Coilcraft	620mA/125°C
L3, L5	10 nH	1.6 x 0.8 mm	LQW18AN10NG00D	Murata	650mA/10nH
L4	10 μ H	2.5 x 2 mm	IFSC1008ABER100M01	Vishay	750mA/0.41 Ω
C1	Cu Shim	0505	—	—	—
C2	20 pF	0505	800A200JTN250XT	ATC	250V/125°C
C3, C7, C16	1 nF	0603	—	—	50V/125°C
C4	1 μ F	0805	CL21B105KBFNNNG	Samsung Electro-Mechanics	50V/125°C
C5	5.6 pF	0603	600S5R6AT250XT	ATC	250V/125°C
C6	100 pF	0603	—	—	250V/125°C
C9, C13	2.2 μ F	1210	—	—	35V/125°C
C10	470 pF	0402	—	—	50V/125°C
C11	100 nF	0805	—	—	50V/125°C
C12	10 nF	0805	—	—	50V/125°C
C14, C24	10 μ F	0603	—	—	10V/125°C
C15	10 pF	0402	—	—	50V/125°C
C17	10 pF	0505	800A100JT250X	ATC	250V/125°C
C18	0.3 pF	0603	600S0R3AT250XT	ATC	250V/ $\pm$ 0.05pF/125°C
C21, C22, C23	10 nF	0603	—	—	50V/125°C
R1, R2	69.8 Ω	1206	—	—	0.25W/0.1%/155°C
R3, R4	3.6 K Ω	0603	—	—	0.2W/0.1%/155°C
R6, R18	0 Ω	0402	—	—	125°C
R7	1.6 M Ω	0402	—	—	0.063W/1%/155°C
R8	115 K Ω	0402	—	—	0.063W/1%/155°C
R9	100 Ω	0402	—	—	125°C
D1	—	SOT23-3	CMPSH-3CE TR	Central Semiconductor	750mA/40V/155°C
ANT, RX, TX	RF CONN	SMA	142-0761-821	Cinch Connectivity Solutions	—
DC CONN	DC CONN	10PIN	—	—	10 pin header

8. MACOM datasheet performance was captured using components from manufacturers shown. These parts are critical to meet specified performance. All other parts must meet ratings specified but do not have specific manufacturer recommendations.

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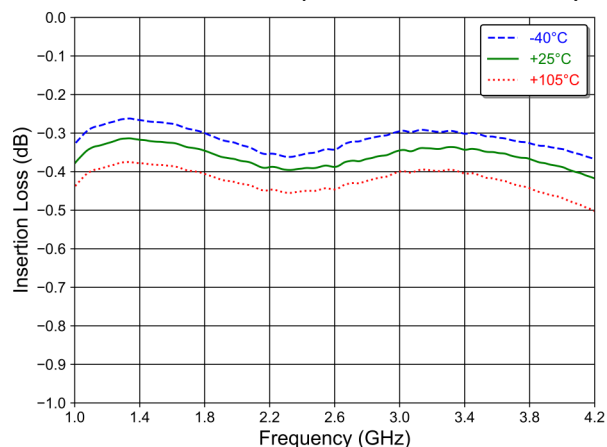


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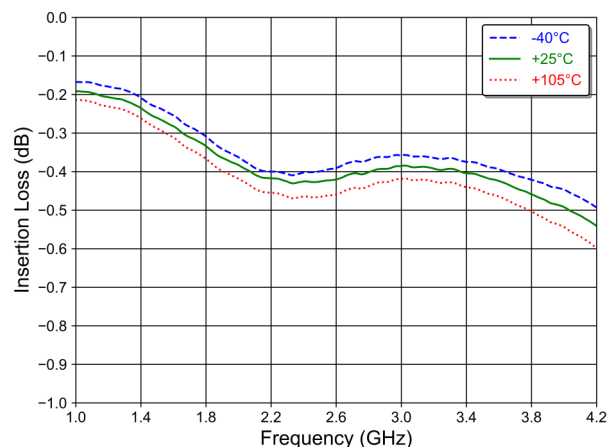
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Typical Performance Curves on the Sample Board optimized for 1.0 - 4.2 GHz
performance VCC = 5 V, P_{IN} = -5 dBm

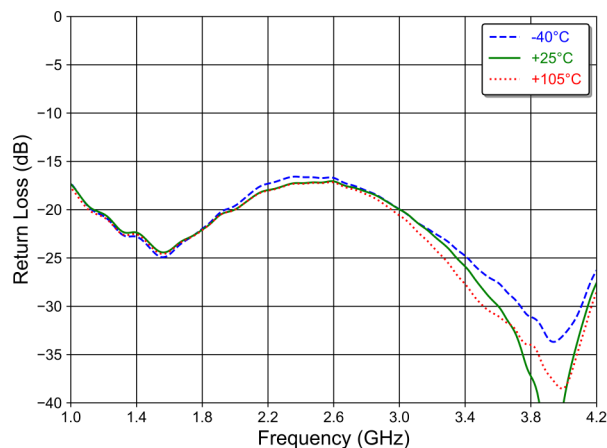
ANT to TX Insertion Loss (PCB loss de-embedded)⁹



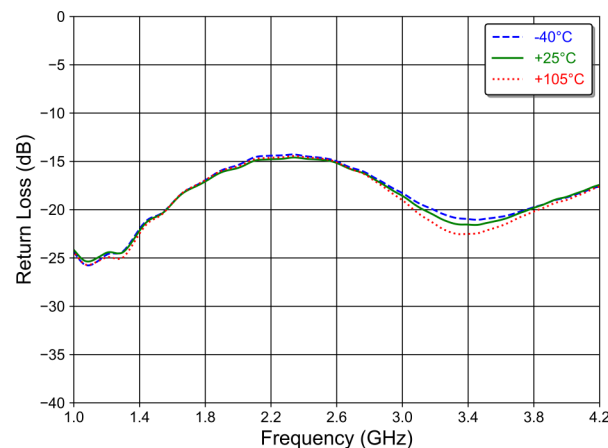
ANT to RX Insertion (PCB loss de-embedded)⁹



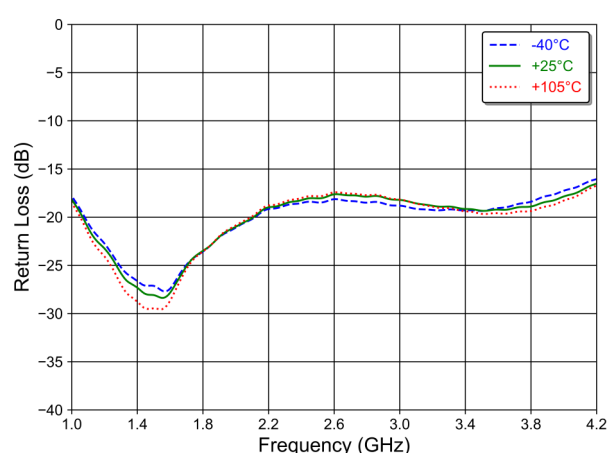
ANT Return Loss in TX ON state



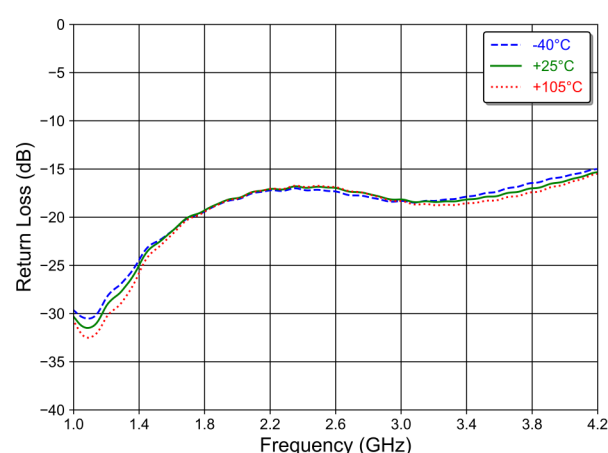
ANT Return Loss in RX ON state



TX Return Loss in TX ON state



RX Return Loss in RX ON state



9. For Insertion Loss plots, RF trace and connector losses are de-embedded .

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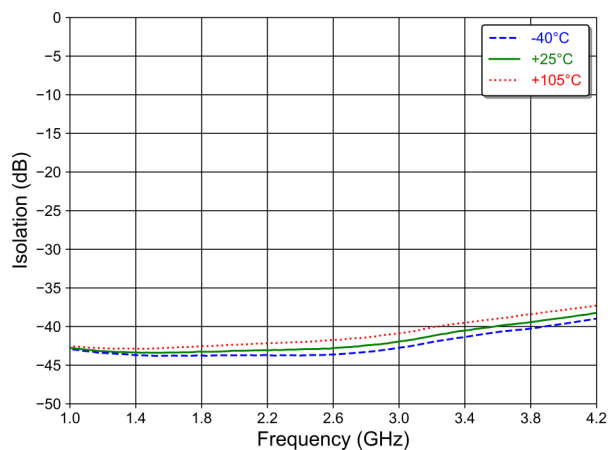


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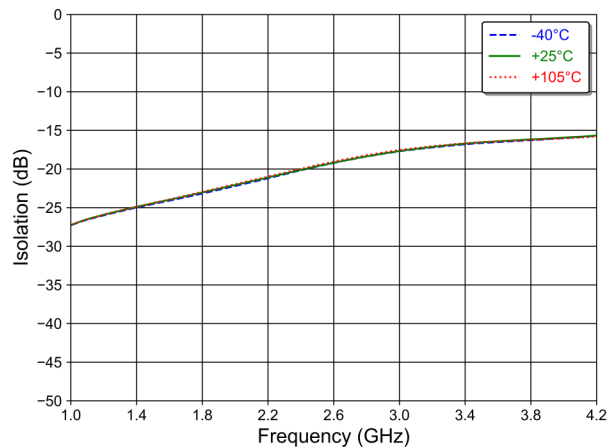
Rev. V2

Typical Performance Curves on the Sample Board optimized for 1 - 4.2 GHz performance. $V_{CC} = 5\text{ V}$, $P_{IN} = -5\text{ dBm}$

ANT to RX Isolation¹⁰



ANT to TX Isolation



10. ANT to RX isolation has strong dependence on board layout.

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Parts List for Optimized Tuning for 2 - 8 GHz¹¹

Component ID	Value	Package	Part Number	Manufacturer	Spec
MAMF-011180	—	HQFN-20LD 5 mm	MAMF-011180	MACOM	—
L1, L2	20 nH	1 x 0.6 mm	LQW15AN20NJ8ZD	Murata	800mA/125°C
L3, L5	10 nH	1.6 x 0.8 mm	LQW18AN10NG00D	Murata	650mA/10nH
L4	10 μ H	2.5 x 2 mm	IFSC1008ABER100M01	Vishay	750mA/0.41 Ω
C1, C2, C17	5.6 pF	0505	800A5R6CT250XT	ATC	250V/ $\pm$ 0.25pF/125°C
C3, C7, C16	1 nF	0603	—	—	50V/125°C
C4	1 μ F	0805	CL21B105KBFNNNG	Samsung Electro-Mechanics	50V/125°C
C5	5.6 pF	0603	600S5R6AT250XT	ATC	250V/125°C
C6	100 pF	0603	—	—	250V/125°C
C9, C13	2.2 μ F	1210	—	—	35V/125°C
C10	470 pF	0402	—	—	50V/125°C
C11	100 nF	0805	—	—	50V/125°C
C12	10 nF	0805	—	—	50V/125°C
C14, C24	10 μ F	0603	—	—	10V/125°C
C15	10 pF	0402	—	—	50V/125°C
C18	DNP	—	—	—	—
C21, C22, C23	10 nF	0603	—	—	50V/125°C
R1, R2	69.8 Ω	1206	—	—	0.25W/0.1%/155°C
R3, R4	3.6 K Ω	0603	—	—	0.2W/0.1%/155°C
R6, R18	0 Ω	0402	—	—	125°C
R7	1.6 M Ω	0402	—	—	0.063W/1%/155°C
R8	115 K Ω	0402	—	—	0.063W/1%/155°C
R9	100 Ω	0402	—	—	125°C
D1	—	SOT23-3	CMPSH-3CE TR	Central Semiconductor	750mA/40V/155°C
ANT, RX, TX	RF CONN	SMA	142-0761-821	Cinch Connectivity Solutions	—
DC CONN	DC CONN	10PIN	—	—	10 pin header

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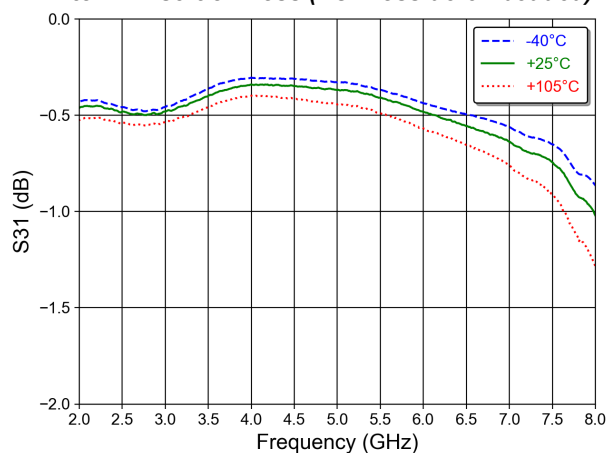


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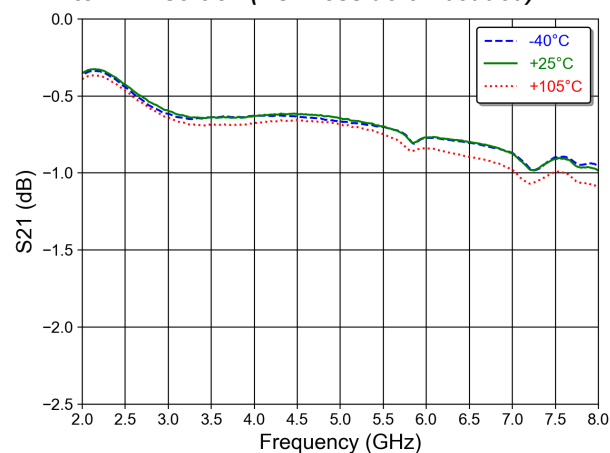
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Typical Performance Curves for 2 - 8 GHz Tuning, $V_{CC} = 5\text{ V}$, $P_{IN} = -5\text{ dBm}$

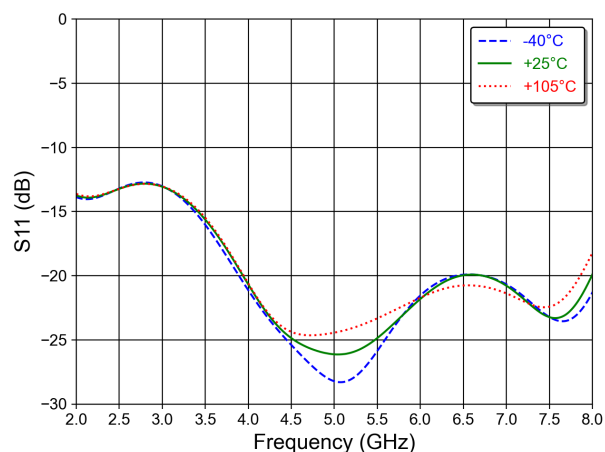
ANT to TX Insertion Loss (PCB loss de-embedded)¹²



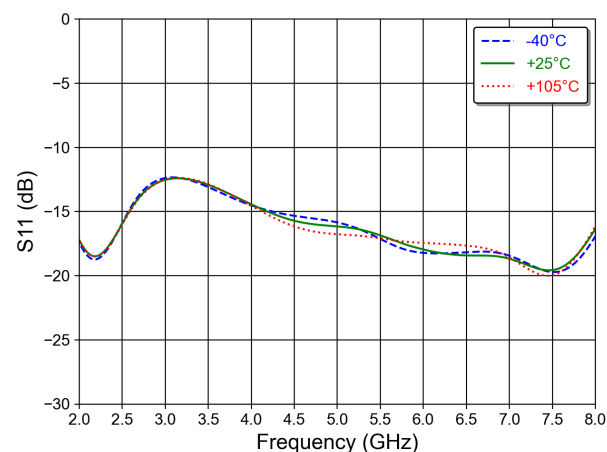
ANT to RX Insertion (PCB loss de-embedded)¹²



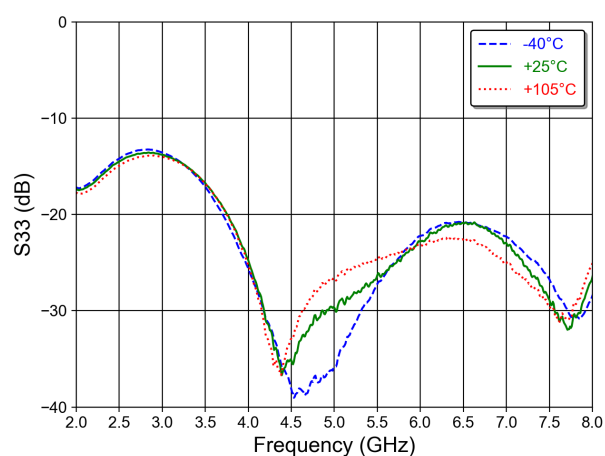
ANT Return Loss in TX ON state



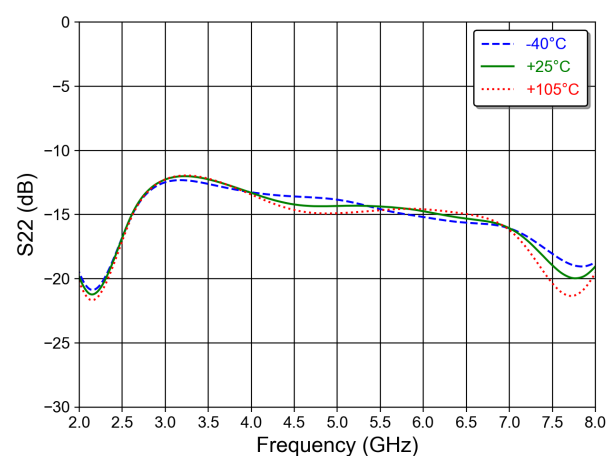
ANT Return Loss in RX ON state



TX Return Loss in TX ON state



RX Return Loss in RX ON state



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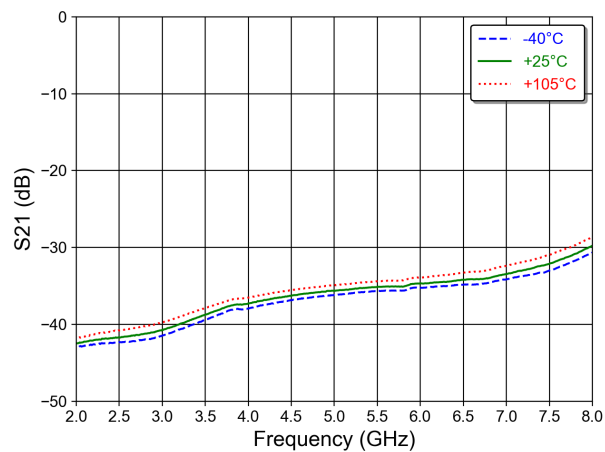


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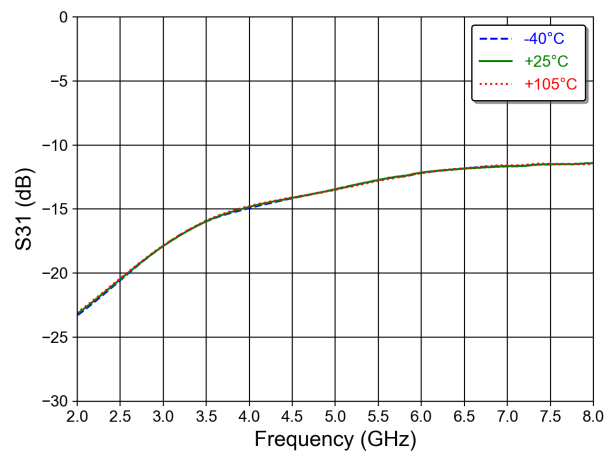
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Typical Performance Curves for 2 - 8 GHz Tuning, $V_{CC} = 5\text{ V}$, $P_{IN} = -5\text{ dBm}$

ANT to RX Isolation¹³



ANT to TX Isolation



13. ANT to RX isolation has strong dependence on board layout.

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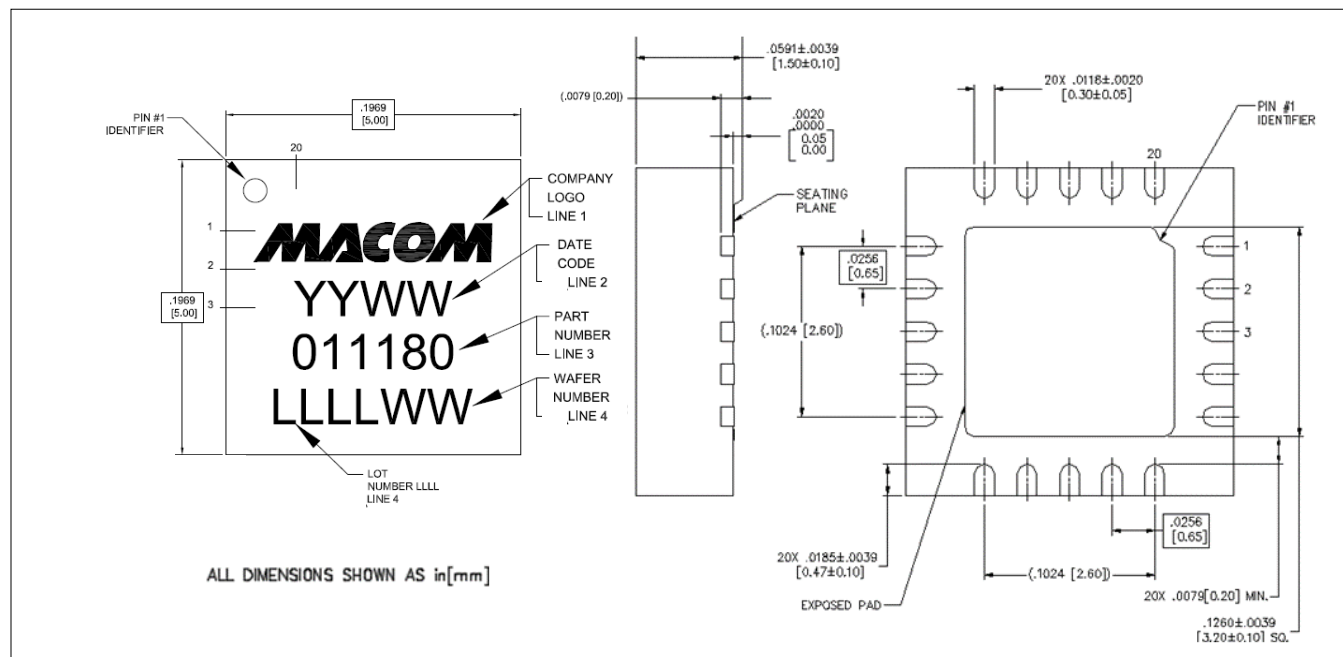
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Lead-Free 5 mm 20-Lead HQFN[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.
Plating is NiPdAuAg

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